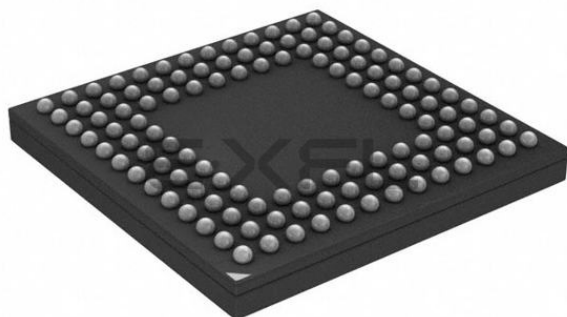




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Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, LINbus, MMC/SD/SDIO, QSPI, SmartCard, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	95
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 16x12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	120-VFBGA
Supplier Device Package	120-BGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg11b840f1024gl120-b

Ordering Code	Flash (kB)	RAM (kB)	DC-DC Converter	USB	Ethernet	QSPI	SDIO	LCD	GPIO	Package	Temp Range
EFM32GG11B520F2048GQ64-A	2048	512	Yes	No	No	No	No	Yes	50	QFP64	-40 to +85°C
EFM32GG11B510F2048GQ64-A	2048	384	Yes	No	No	No	No	Yes	50	QFP64	-40 to +85°C
EFM32GG11B520F2048GM64-A	2048	512	Yes	No	No	No	No	Yes	53	QFN64	-40 to +85°C
EFM32GG11B510F2048GM64-A	2048	384	Yes	No	No	No	No	Yes	53	QFN64	-40 to +85°C
EFM32GG11B520F2048IQ64-A	2048	512	Yes	No	No	No	No	Yes	50	QFP64	-40 to +125°C
EFM32GG11B510F2048IQ64-A	2048	384	Yes	No	No	No	No	Yes	50	QFP64	-40 to +125°C
EFM32GG11B520F2048IM64-A	2048	512	Yes	No	No	No	No	Yes	53	QFN64	-40 to +125°C
EFM32GG11B510F2048IM64-A	2048	384	Yes	No	No	No	No	Yes	53	QFN64	-40 to +125°C
EFM32GG11B420F2048GL120-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	93	BGA120	-40 to +85°C
EFM32GG11B420F2048IL120-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	93	BGA120	-40 to +125°C
EFM32GG11B420F2048GL112-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	87	BGA112	-40 to +85°C
EFM32GG11B420F2048IL112-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	87	BGA112	-40 to +125°C
EFM32GG11B420F2048GQ100-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	83	QFP100	-40 to +85°C
EFM32GG11B420F2048IQ100-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	83	QFP100	-40 to +125°C
EFM32GG11B420F2048GQ64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	50	QFP64	-40 to +85°C
EFM32GG11B420F2048GM64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	53	QFN64	-40 to +85°C
EFM32GG11B420F2048IQ64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	50	QFP64	-40 to +125°C
EFM32GG11B420F2048IM64-A	2048	512	No	Yes	Yes	Yes	Yes	Yes	53	QFN64	-40 to +125°C
EFM32GG11B320F2048GL112-A	2048	512	No	No	No	No	No	Yes	90	BGA112	-40 to +85°C
EFM32GG11B310F2048GL112-A	2048	384	No	No	No	No	No	Yes	90	BGA112	-40 to +85°C
EFM32GG11B320F2048GQ100-A	2048	512	No	No	No	No	No	Yes	86	QFP100	-40 to +85°C
EFM32GG11B310F2048GQ100-A	2048	384	No	No	No	No	No	Yes	86	QFP100	-40 to +85°C
EFM32GG11B120F2048GQ64-A	2048	512	No	No	No	No	No	No	53	QFP64	-40 to +85°C
EFM32GG11B110F2048GQ64-A	2048	384	No	No	No	No	No	No	53	QFP64	-40 to +85°C
EFM32GG11B120F2048GM64-A	2048	512	No	No	No	No	No	No	56	QFN64	-40 to +85°C
EFM32GG11B110F2048GM64-A	2048	384	No	No	No	No	No	No	56	QFN64	-40 to +85°C
EFM32GG11B120F2048IQ64-A	2048	512	No	No	No	No	No	No	53	QFP64	-40 to +125°C
EFM32GG11B110F2048IQ64-A	2048	384	No	No	No	No	No	No	53	QFP64	-40 to +125°C
EFM32GG11B120F2048IM64-A	2048	512	No	No	No	No	No	No	56	QFN64	-40 to +125°C
EFM32GG11B110F2048IM64-A	2048	384	No	No	No	No	No	No	56	QFN64	-40 to +125°C

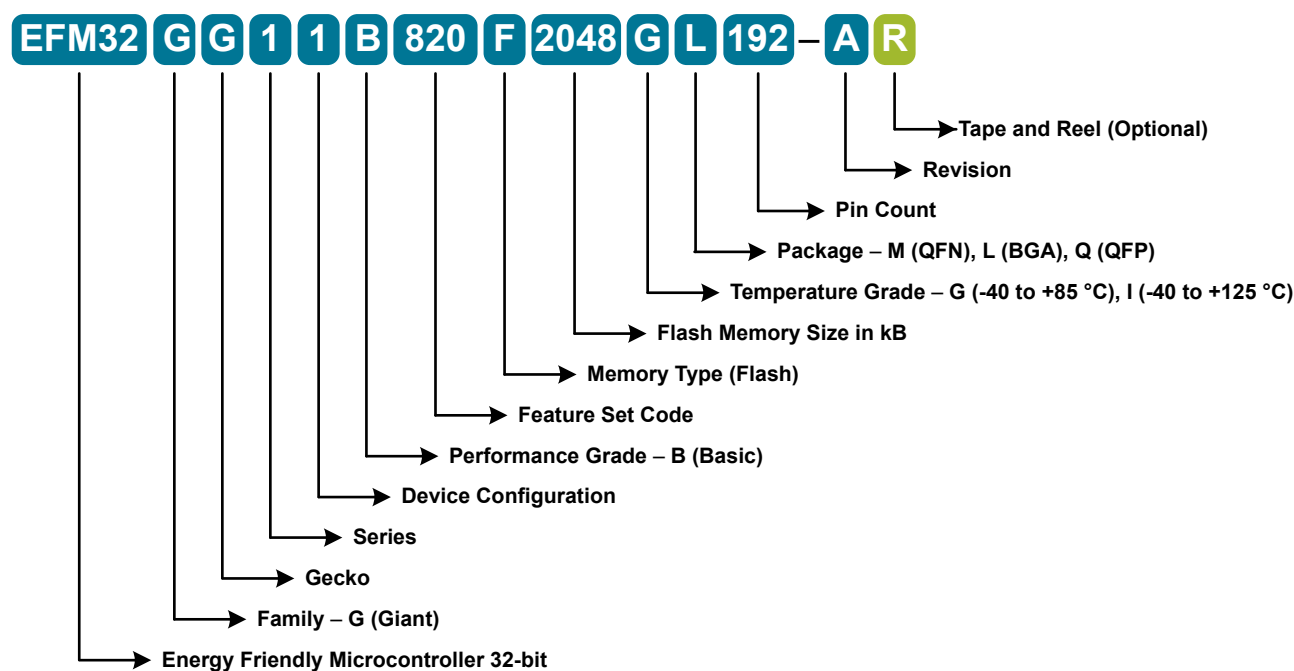


Figure 2.1. Ordering Code Key

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4.1.8 Wake Up Times

Table 4.10. Wake Up Times

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Wake up time from EM1	t_{EM1_WU}		—	3	—	AHB Clocks
Wake up from EM2	t_{EM2_WU}	Code execution from flash	—	11.8	—	μs
		Code execution from RAM	—	4.1	—	μs
Wake up from EM3	t_{EM3_WU}	Code execution from flash	—	11.8	—	μs
		Code execution from RAM	—	4.1	—	μs
Wake up from EM4H ¹	t_{EM4H_WU}	Executing from flash	—	94	—	μs
Wake up from EM4S ¹	t_{EM4S_WU}	Executing from flash	—	294	—	μs
Time from release of reset source to first instruction execution	t_{RESET}	Soft Pin Reset released	—	55	—	μs
		Any other reset released	—	359	—	μs
Power mode scaling time	t_{SCALE}	VSCALE0 to VSCALE2, HFCLK = 19 MHz ^{4 2}	—	31.8	—	μs
		VSCALE2 to VSCALE0, HFCLK = 19 MHz ³	—	4.3	—	μs

Note:

1. Time from wake up request until first instruction is executed. Wakeup results in device reset.
2. VSCALE0 to VSCALE2 voltage change transitions occur at a rate of 10 mV/ μs for approximately 20 μs . During this transition, peak currents will be dependent on the value of the DECOUPLE output capacitor, from 35 mA (with a 1 μF capacitor) to 70 mA (with a 2.7 μF capacitor).
3. Scaling down from VSCALE2 to VSCALE0 requires approximately 2.8 μs + 29 HFCLKs.
4. Scaling up from VSCALE0 to VSCALE2 requires approximately 30.3 μs + 28 HFCLKs.

4.1.10 Oscillators

4.1.10.1 Low-Frequency Crystal Oscillator (LFXO)

Table 4.12. Low-Frequency Crystal Oscillator (LFXO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Crystal frequency	f_{LFXO}		—	32.768	—	kHz
Supported crystal equivalent series resistance (ESR)	ESR_{LFXO}		—	—	70	k Ω
Supported range of crystal load capacitance ¹	$C_{\text{LFXO_CL}}$		6	—	18	pF
On-chip tuning cap range ²	$C_{\text{LFXO_T}}$	On each of LFX TAL_N and LFX TAL_P pins	8	—	40	pF
On-chip tuning cap step size	SS_{LFXO}		—	0.25	—	pF
Current consumption after startup ³	I_{LFXO}	ESR = 70 k Ω m, C_L = 7 pF, GAIN ⁴ = 2, AGC ⁴ = 1	—	273	—	nA
Start- up time	t_{LFXO}	ESR = 70 k Ω m, C_L = 7 pF, GAIN ⁴ = 2	—	308	—	ms

Note:

1. Total load capacitance as seen by the crystal.
2. The effective load capacitance seen by the crystal will be $C_{\text{LFXO_T}}/2$. This is because each XTAL pin has a tuning cap and the two caps will be seen in series by the crystal.
3. Block is supplied by AVDD if ANASW = 0, or DVDD if ANASW=1 in EMU_PWRCTRL register.
4. In CMU_LFXOCTRL register.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply current, continuous conversions, WARMUP-MODE=KEEPCSENWARM	I _{CSEN_ACTIVE}	SAR or Delta Modulation conversions of 33 pF capacitor, CS0CG=0 (Gain = 10x), always on	—	90.5	—	μA
HFPERCLK supply current	I _{CSEN_HFPERCLK}	Current contribution from HFPERCLK when clock to CSEN block is enabled.	—	2.25	—	μA/MHz

Note:

1. Current is specified with a total external capacitance of 33 pF per channel. Average current is dependent on how long the module is actively sampling channels within the scan period, and scales with the number of samples acquired. Supply current for a specific application can be estimated by multiplying the current per sample by the total number of samples per period (total_current = single_sample_current * (number_of_channels * accumulation)).

EBI Read Enable Output Timing

Timing applies to both EBI_REn and EBI_NANDREn for all addressing modes and both polarities. Output timing for EBI_AD applies only to multiplexed addressing modes D8A24ALE and D16A16ALE. All numbers are based on route locations 0,1,2 only (with all EBI alternate functions using the same location at the same time). Timing is specified at 10% and 90% of IOVDD, 25 pF external loading, and slew rate for all GPIO set to 6.

Table 4.38. EBI Read Enable Output Timing

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output hold time, from trailing EBI_REn / EBI_NANDREn edge to EBI_AD, EBI_A, EBI_CS _n , EBI_BLn invalid	t _{OH_REn}	IOVDD ≥ 1.62 V	-23 + (RDHOLD * t _{HFCOR-ECLK})	—	—	ns
		IOVDD ≥ 3.0 V	-13 + (RDHOLD * t _{HFCOR-ECLK})	—	—	ns
Output setup time, from EBI_AD, EBI_A, EBI_CS _n , EBI_BLn valid to leading EBI_REn / EBI_NANDREn edge ¹	t _{OSU_REn}	IOVDD ≥ 1.62 V	-12 + (RDSETUP * t _{HFCOR-ECLK})	—	—	ns
		IOVDD ≥ 3.0 V	-11 + (RDSETUP * t _{HFCOR-ECLK})	—	—	ns
EBI_REn pulse width ^{1 2}	t _{WIDTH_REn}	IOVDD ≥ 1.62 V	-6 + (MAX(1, RDSTRB) * t _{HFCOR-ECLK})	—	—	ns
		IOVDD ≥ 3.0 V	-4 + (MAX(1, RDSTRB) * t _{HFCOR-ECLK})	—	—	ns

Note:

1. The figure shows the timing for the case that the half strobe length functionality is not used, i.e. HALFRE=0. The leading edge of EBI_REn can be moved to the right by setting HALFRE=1. This decreases the length of t_{WIDTH_REn} and increases the length of t_{OSU_REn} by 1/2 * t_{HFCLKNODIV}.
2. When page mode is used, RDSTRB is replaced by RDPA for page hits.

EBI TFT Output Timing

All numbers are based on route locations 0,1,2 only (with all EBI alternate functions using the same location at the same time). Timing is specified at 10% and 90% of IOVDD, 25 pF external loading, and slew rate for all GPIO set to 6.

Table 4.39. EBI TFT Output Timing

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output hold time, EBI_DCLK to EBI_AD invalid	t_{OH_DCLK}	IOVDD $\geq$ 1.62 V	-23 + (TFTHOLD * t_{HFCOR-} ECLK)	—	—	ns
		IOVDD $\geq$ 3.0 V	-12 + (TFTHOLD * t_{HFCOR-} ECLK)	—	—	ns
Output setup time, EBI_AD valid to EBI_DCLK	t_{OSU_DCLK}	IOVDD $\geq$ 1.62 V	-11 + (TFTSET- UP * t_{HFCOR-} ECLK)	—	—	ns
		IOVDD $\geq$ 3.0 V	-9 + (TFTSET- UP * t_{HFCOR-} ECLK)	—	—	ns

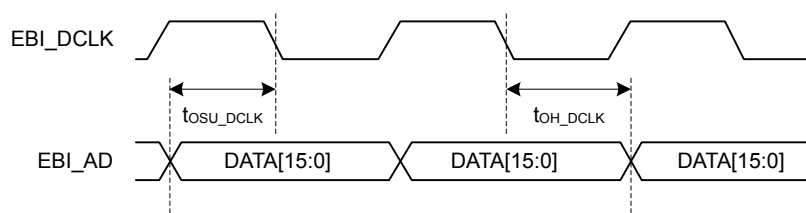
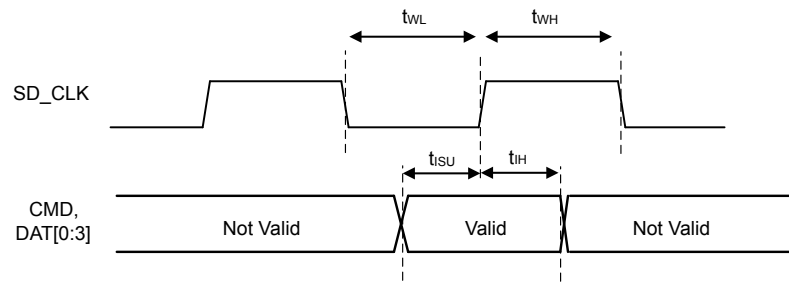
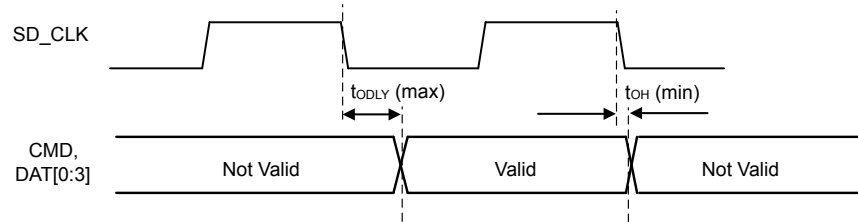


Figure 4.6. EBI TFT Output Timing

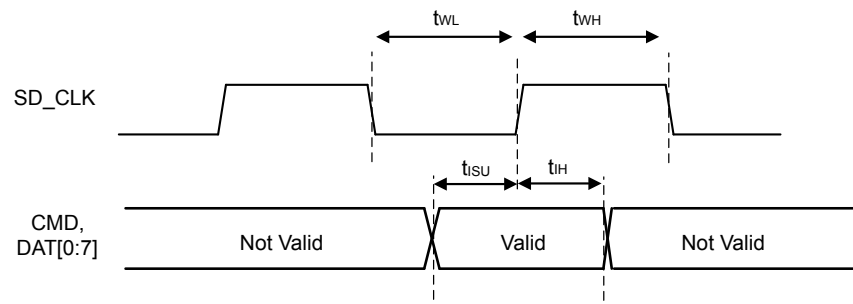


Input Timing

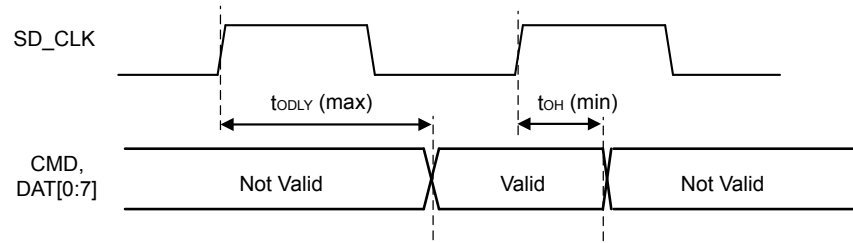


Output Timing

Figure 4.13. SDIO DS Mode Timing

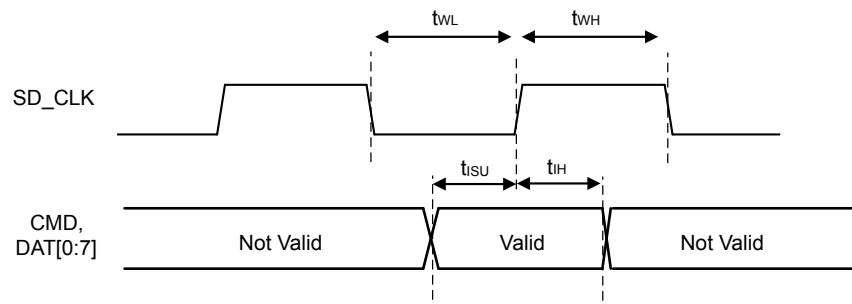


Input Timing

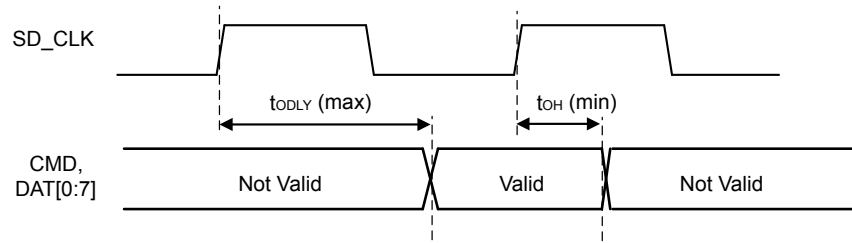


Output Timing

Figure 4.15. SDIO SDR Mode Timing

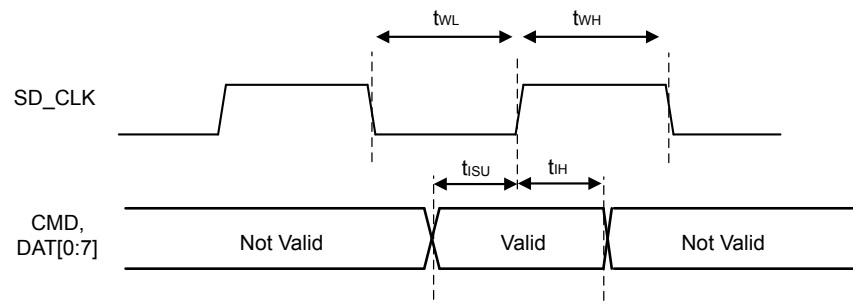


Input Timing

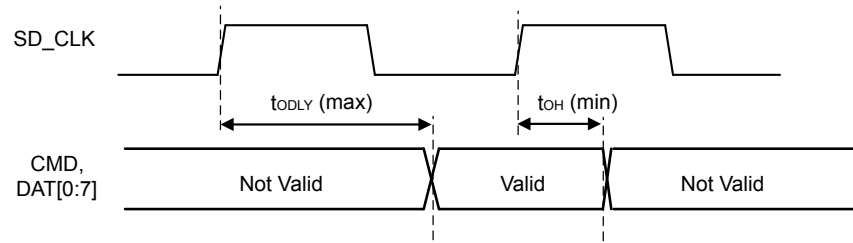


Output Timing

Figure 4.17. SDIO MMC SDR Mode Timing



Input Timing



Output Timing

Figure 4.18. SDIO MMC SDR Mode Timing

4.1.28.2 QSPI DDR Mode

QSPI DDR Mode Timing (Location 0)

Timing is specified with voltage scaling disabled, PHY-mode, route location 0 only, TX DLL = 35, RX DLL = 70, 20-25 pF loading per GPIO, and slew rate for all GPIO set to 6, DRIVESTRENGTH = STRONG.

Table 4.56. QSPI DDR Mode Timing (Location 0)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Half SCLK period	T/2	HFXO	$(1/F_{SCLK})^*$ 0.4 - 0.4	—	—	ns
		HFRCO, AUXHFRCO, USHFRCO	$(1/F_{SCLK})^*$ 0.44	—	—	ns
Output valid	t _{OV}		—	—	T/2 - 5.0	ns
Output hold	t _{OH}		T/2 - 39.4	—	—	ns
Input setup	t _{SU}		33.1	—	—	ns
Input hold	t _H		-0.9	—	—	ns

5. Pin Definitions

5.1 EFM32GG11B8xx in BGA192 Device Pinout

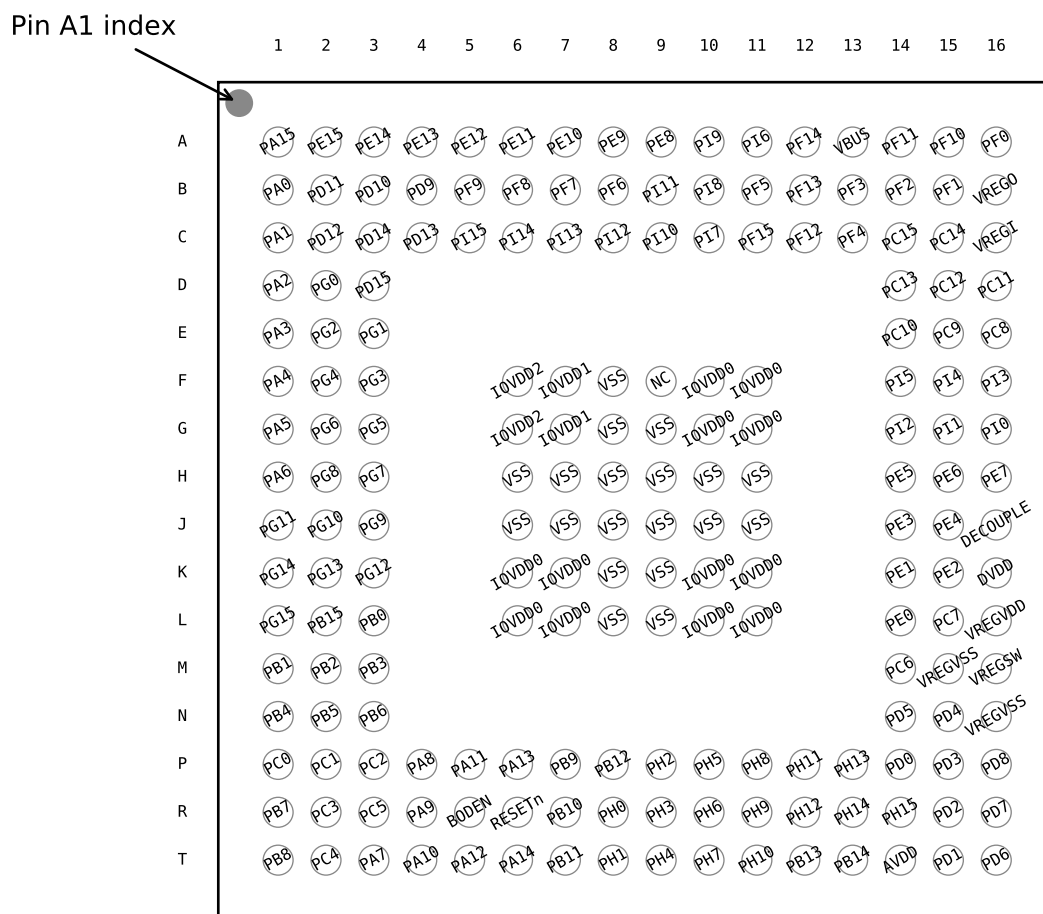


Figure 5.1. EFM32GG11B8xx in BGA192 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.20 GPIO Functionality Table](#) or [5.21 Alternate Functionality Overview](#).

Table 5.1. EFM32GG11B8xx in BGA192 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA15	A1	GPIO	PE15	A2	GPIO
PE14	A3	GPIO	PE13	A4	GPIO
PE12	A5	GPIO	PE11	A6	GPIO
PE10	A7	GPIO	PE9	A8	GPIO
PE8	A9	GPIO	PI9	A10	GPIO (5V)
PI6	A11	GPIO (5V)	PF14	A12	GPIO (5V)

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
IOVDD1	F7 G7	Digital IO power supply 1.	VSS	F8 G8 G9 H6 H7 H8 H9 H10 H11 J6 J7 J8 J9 J10 J11 K8 K9 L8 L9	Ground
NC	F9	No Connect.	IOVDD0	F10 F11 G10 G11 K6 K7 K10 K11 L6 L7 L10 L11	Digital IO power supply 0.
PI5	F14	GPIO (5V)	PI4	F15	GPIO (5V)
PI3	F16	GPIO (5V)	PA5	G1	GPIO
PG6	G2	GPIO (5V)	PG5	G3	GPIO (5V)
PI2	G14	GPIO (5V)	PI1	G15	GPIO (5V)
PI0	G16	GPIO (5V)	PA6	H1	GPIO
PG8	H2	GPIO (5V)	PG7	H3	GPIO (5V)
PE5	H14	GPIO	PE6	H15	GPIO
PE7	H16	GPIO	PG11	J1	GPIO (5V)
PG10	J2	GPIO (5V)	PG9	J3	GPIO (5V)
PE3	J14	GPIO	PE4	J15	GPIO
DECOUPLE	J16	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PG14	K1	GPIO
PG13	K2	GPIO	PG12	K3	GPIO
PE1	K14	GPIO (5V)	PE2	K15	GPIO
DVDD	K16	Digital power supply.	PG15	L1	GPIO (5V)
PB15	L2	GPIO (5V)	PB0	L3	GPIO
PE0	L14	GPIO (5V)	PC7	L15	GPIO
VREGVDD	L16	Voltage regulator VDD input	PB1	M1	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC4	13	GPIO	PC5	14	GPIO
PB7	15	GPIO	PB8	16	GPIO
PA8	17	GPIO	PA12	18	GPIO (5V)
PA14	19	GPIO	RESETn	20	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	21	GPIO	PB12	22	GPIO
AVDD	24	Analog power supply.	PB13	25	GPIO
PB14	26	GPIO	PD0	28	GPIO (5V)
PD1	29	GPIO	PD2	30	GPIO (5V)
PD3	31	GPIO	PD4	32	GPIO
PD5	33	GPIO	PD6	34	GPIO
PD8	35	GPIO	VREGVSS	36	Voltage regulator VSS
VREGSW	37	DCDC regulator switching node	VREGVDD	38	Voltage regulator VDD input
DVDD	39	Digital power supply.	DECOUPLE	40	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	41	GPIO	PE5	42	GPIO
PE6	43	GPIO	PE7	44	GPIO
VREGI	45	Input to 5 V regulator.	VREGO	46	Decoupling for 5 V regulator and regulator output. Power for USB PHY in USB-enabled OPNs
PF10	47	GPIO (5V)	PF11	48	GPIO (5V)
PF0	49	GPIO (5V)	PF1	50	GPIO (5V)
PF2	51	GPIO	VBUS	52	USB VBUS signal and auxiliary input to 5 V regulator.
PF12	53	GPIO	PF5	54	GPIO
PE8	57	GPIO	PE9	58	GPIO
PE10	59	GPIO	PE11	60	GPIO
PE12	61	GPIO	PE13	62	GPIO
PE14	63	GPIO	PE15	64	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).

GPIO Name	Pin Alternate Functionality / Description				
	Analog	EBI	Timers	Communication	Other
PD13		EBI_ARDY #1	TIM2_CDTI0 #1 TIM3_CC1 #6 WTIM0_CC1 #1	ETH_MDIO #1 US4_CTS #1 US5_CLK #1	ETM_TD1 #1
PI15				CAN1_TX #7 US3_CS #5	
PI14				CAN1_RX #7 US3_CLK #5	
PI13				CAN0_TX #7 US3_RX #5	
PI12				CAN0_RX #7 US3_TX #5	
PI10		EBI_A15 #2	TIM4_CC2 #3	US4_CTS #3	
PI7		EBI_A12 #2	TIM1_CC1 #7 TIM4_CC2 #2 WTIM3_CC1 #5	US4_RX #3	
PF15	BUSCY BUSDX		TIM1_CC2 #6 TIM4_CC2 #1 WTIM3_CC2 #7	US5_TX #2 I2C2_SDA #5	
PF12	BUSDY BUSCX	EBI_NANDREn #5	TIM4_CC2 #0 TIM1_CC3 #5 TIM5_CC0 #7 WTIM3_CC2 #6	US5_CS #2 I2C2_SCL #3 USB_ID	
PF4	BUSDY BUSCX LCD_SEG2	EBI_WEn #0 EBI_WEn #5	TIM4_CC1 #0 TIM0_CDTI1 #2 TIM1_CC2 #5 WTIM3_CC1 #6	US1_RTS #2 I2C2_SDA #3	PRS_CH1 #1
PC15	VDAC0_OUT1ALT / OPA1_OUTALT #3 BUSACMP1Y BU- SACMP1X	EBI_NANDREn #4	TIM0_CDTI2 #1 TIM1_CC2 #0 WTIM0_CC0 #4 LE- TIM0_OUT1 #5	US0_CLK #3 US1_CLK #3 US3_RTS #3 U0_RX #3 U1_RTS #0 LEU0_RX #5 I2C2_SCL #1	LES_CH15 PRS_CH1 #2 ACMP3_O #1 DBG_SWO #1
PC14	VDAC0_OUT1ALT / OPA1_OUTALT #2 BUSACMP1Y BU- SACMP1X	EBI_NANDWEn #4	TIM0_CDTI1 #1 TIM1_CC1 #0 TIM1_CC3 #4 TIM5_CC0 #6 WTIM3_CC0 #3 LE- TIM0_OUT0 #5 PCNT0_S1IN #0	US0_CS #3 US1_CS #3 US2_RTS #3 US3_CS #2 U0_TX #3 U1_CTS #0 LEU0_TX #5 I2C2_SDA #1	LES_CH14 PRS_CH0 #2 ACMP3_O #2
PA2	BUSBY BUSAX LCD_SEG15	EBI_AD11 #0 EBI_DTEN #3	TIM0_CC2 #0 TIM3_CC2 #4	ETH_RMIIRXD0 #0 ETH_MIITXD2 #0 SDIO_DAT2 #1 US1_RX #6 US3_CLK #0 QSPIO_DQ0 #1	CMU_CLK0 #0 PRS_CH8 #1 ETM_TD0 #3
PG0	BUSACMP2Y BU- SACMP2X	EBI_AD00 #2	TIM6_CC0 #0 TIM2_CDTI0 #3 WTIM0_CDTI1 #1 LETIM1_OUT0 #6	ETH_MIITXCLK #1 US3_TX #4 QSPIO_SCLK #2	CMU_CLK2 #3

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LES_ALTEX6	0: PE12		LESENSE alternate excite output 6.
LES_ALTEX7	0: PE13		LESENSE alternate excite output 7.
LES_CH0	0: PC0		LESENSE channel 0.
LES_CH1	0: PC1		LESENSE channel 1.
LES_CH2	0: PC2		LESENSE channel 2.
LES_CH3	0: PC3		LESENSE channel 3.
LES_CH4	0: PC4		LESENSE channel 4.
LES_CH5	0: PC5		LESENSE channel 5.
LES_CH6	0: PC6		LESENSE channel 6.
LES_CH7	0: PC7		LESENSE channel 7.
LES_CH8	0: PC8		LESENSE channel 8.
LES_CH9	0: PC9		LESENSE channel 9.
LES_CH10	0: PC10		LESENSE channel 10.

	APORT4Y	APORT3Y	APORT2Y	APORT1Y	Port
	BUSDY	BUSCY	BUSBY	BUSAY	Bus
		PF15		PB15	CH31
	PF14		PB14		CH30
		PF13		PB13	CH29
	PF12		PB12		CH28
		PF11		PB11	CH27
	PF10		PB10		CH26
		PF9		PB9	CH25
	PF8				CH24
		PF7			CH23
	PF6		PB6		CH22
		PF5		PB5	CH21
	PF4		PB4		CH20
		PF3		PB3	CH19
	PF2		PB2		CH18
		PF1		PB1	CH17
	PF0		PB0		CH16
		PE15		PA15	CH15
	PE14		PA14		CH14
		PE13		PA13	CH13
	PE12		PA12		CH12
		PE11		PA11	CH11
	PE10		PA10		CH10
		PE9		PA9	CH9
	PE8		PA8		CH8
		PE7		PA7	CH7
	PE6		PA6		CH6
		PE5		PA5	CH5
	PE4		PA4		CH4
				PA3	CH3
			PA2		CH2
		PE1		PA1	CH1
	PE0		PA0		CH0
VDAC0_OUT1 / OPA1_OUT					

7.3 BGA152 Package Marking



Figure 7.3. BGA152 Package Marking

The package marking consists of:

- P P P P P P P P P P – The part number designation.
- T T T T T T – A trace or manufacturing code. The first letter is the device revision.
- Y Y – The last 2 digits of the assembly year.
- W W – The 2-digit workweek when the device was assembled.